

L Number	Hits	Search Text	DB	Time stamp
2	30	memory same resistant same material same plug	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 16:57
3	35	memory same amorphous adj dielectric	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 16:50
5	38	memory same resistant near2 material same contact	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 16:58